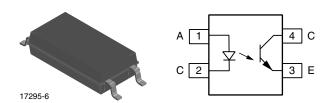


Vishay Semiconductors

Optocoupler, Phototransistor Output, Low Input Current, SOP-4L, Long Mini-Flat Package



DESCRIPTION

The VOL618A has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a SOP-4 pin wide body package.

It features a high current transfer ratio, low coupling capacitance, and high isolation voltage.

The coupling device is designed for signal transmission between two electrically separated circuits.

FEATURES

- · Low profile package
- High collector emitter voltage, V_{CEO} = 80 V
- Isolation test voltage, 5000 V_{RMS}
- Isolation voltage V_{IROM} = 1050 V_{peak}
- · Low coupling capacitance
- High common mode transient immunity
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb-free



GREEN (5-2008)**

Nate

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

APPLICATIONS

- Telecom
- · Industrial controls
- · Battery powered equipment
- · Office machines
- Programmable controllers

AGENCY APPROVALS

- UL1577, file no. E76222
- cUL CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending), available with option 1
- BSI: EN 60065:2002, EN 60950-1:2006
- FIMKO

ORDERING INFORMATIO	N				
V O L 6 1 PART NUMBE		PACKAGE OPTION TAPE AND REEL	SOP-4L		
AGENCY CERTIFIED/PACKAGE		CTR (%)			
AGENCY CERTIFIED/FACKAGE	1 mA				
UL, cUL, BSI, FIMKO	63 to 125	100 to 200	160 to 320		
SOP-4L, mini-flat, long	VOL618A-2T	VOL618A-3T	VOL618A-4T		
VDE, UL, cUL, BSI, FIMKO	63 to 125	100 to 200	160 to 320		
SOP-4L, mini-flat, long	VOL618A-2X001T	VOL618A-3X001T	VOL618A-4X001T		



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Power dissipation		P _{diss}	100	mW		
Forward current		l _F	60	mA		
OUTPUT						
Collector emitter voltage		V_{CEO}	80	V		
Emitter collector voltage		V _{ECO}	7	V		
Collector current		I _C	50	mA		
Collector current	$t_p/T = 0.5, t_p < 10 \text{ ms}$	I _C	100	mA		
Power dissipation		P _{diss}	150	mW		
COUPLER						
Isolation test voltage between emitter and detector		V _{ISO}	5000	V_{RMS}		
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω		
isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω		
Storage temperature range		T _{stg}	- 55 to + 125	°C		
Ambient temperature range		T _{amb}	- 55 to + 100	°C		
Soldering temperature (1)	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T _{sld}	260	°C		

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 5 mA		V_{F}		1.16	1.5	V
Capacitance	$V_R = 0 V, f = 1 MHz$		Co		45		pF
OUTPUT							
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, I_F = 0 \text{ A}$		I _{CEO}		10	200	nA
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz		C _{CE}		7		pF
COUPLER							
	$I_C = 0.32 \text{ mA}, I_F = 1 \text{ mA}$	VOL618A-2	V _{CEsat}		0.25	0.4	V
Collector emitter saturation voltage	$I_C = 0.5 \text{ mA}, I_F = 1 \text{ mA}$	VOL618A-3	V _{CEsat}		0.25	0.4	V
Vollago	I _C = 0.8 mA, I _F = 1 mA	VOL618A-4	V _{CEsat}		0.25	0.4	V
Coupling capacitance	f = 1 MHz		C _C		0.25		pF

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	METER TEST CONDITION PART SYMBOL MIN. TYP. MAX. UNIT								
	I _F = 1 mA, V _{CE} = 5 V	VOL618A-2	CTR	63		125	%		
I _C /I _F		VOL618A-3	CTR	100		200	%		
		VOL618A-4	CTR	160		320	%		



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SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	ARAMETER TEST CONDITION SYMBOL MIN. TYP. MAX. UN						
Turn on time	$V_{CC} = 5 \text{ V}, I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega$	t _{on}		6		μs	
Rise time	$V_{CC} = 5 \text{ V}, I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega$	t _r		3.5		μs	
Turn off time	$V_{CC} = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$	t _{off}		5.5		μs	
Fall time	$V_{CC} = 5 \text{ V}, I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega$	t _f		5		μs	

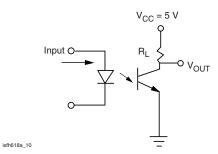


Fig. 1 - Test Circuit

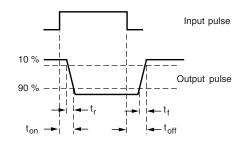


Fig. 2 - Test Circuit and Waveforms

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V _{pd}	2			kV
Partial discharge test voltage -	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$	V _{IOTM}	8			kV
lot test (sample test)	(see figure 4)	V_{pd}	1.68			kV
Insulation voltage	For lifetime	V_{IROM}			1050	V _{peak}
Insulation resistance	V _{IO} = 500 V	R _{IO}	10 ¹²			Ω
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹			Ω
	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹			Ω
Forward current		I _{si}			130	mA
Power dissipation		P _{SO}			265	mW
Rated impulse voltage		V_{IOTM}			8	kV
Safety temperature		T _{si}			150	°C
Clearance distance			8.00			mm
Creepage distance			8.00			mm
Insulation distance (internal)			0.40			mm

Note

 According to DIN EN 60747-5-2 (VDE 0884) (see figure 4). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

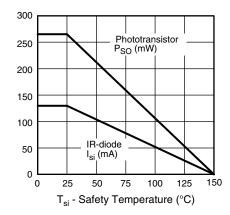


Fig. 3 - Derating Diagram

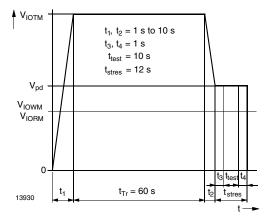
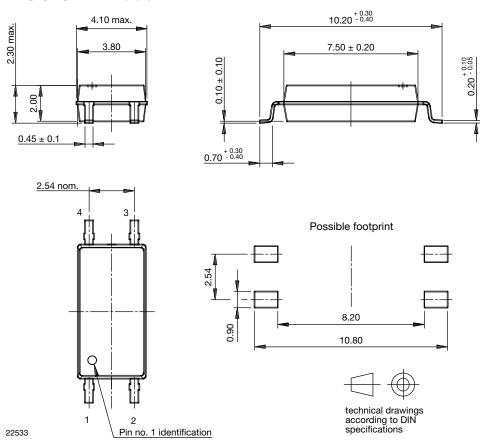


Fig. 4 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-2; IEC60747-5-5



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PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (example)



Notes

- Only option 1 is reflected in the package marking with the characters "X1".
- Tape and reel suffix (T) is not part of the package marking.

Legal Disclaimer Notice



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